

GW Production in Solar Frontier K.K. : Current Status and Future Prospect

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Solar Frontier K.K.
(and Showa Shell Sekiyu K.K.)

Sincere appreciation for your warm encouragement and strong support to Japan, especially the people in Tohoku District, who had sudden change of the life.

We would not be beaten by the current tough situation until the ordinary life is back to us.

Outline

- **Current Status**
- **Future Prospect**
- **Conclusions**



Showa Shell Sekiyu Group



Head Office: Daiba Frontier Building
In Tokyo



Showa Shell Sekiyu K.K.

Oil Refining
and Domestic
Sales

**Saudi
Aramco**



15%

**Royal
Dutch
Shell**



35%

**General
Stockholders**



50%

100% Subsidiary,
Solar-PV related Business: Manufacturing and Sales



Solar Frontier K.K.

100%

Solar Frontier Europe, GmbH

100%

Solar Frontier Americas, Inc.



Showa Shell Sekiyu K.K. with Solar-PV

1978: Start the R&D of Solar-PV system with single crystal Si PV modules.

1988: Kushiya started the CIS research as a visiting researcher of the R&D team in ARCO Solar, Inc.

1993: Start the NEDO PV R&D projects on the development of CIS-based thin-film PV technology.

2005: Make a decision on the commercialization with CIS-based thin-film PV technology.

2006: Establish the Showa Shell Solar K.K.

2007: Start the commercial production of CIS-based thin-film PV modules with 20 MW/a in Miyazaki.

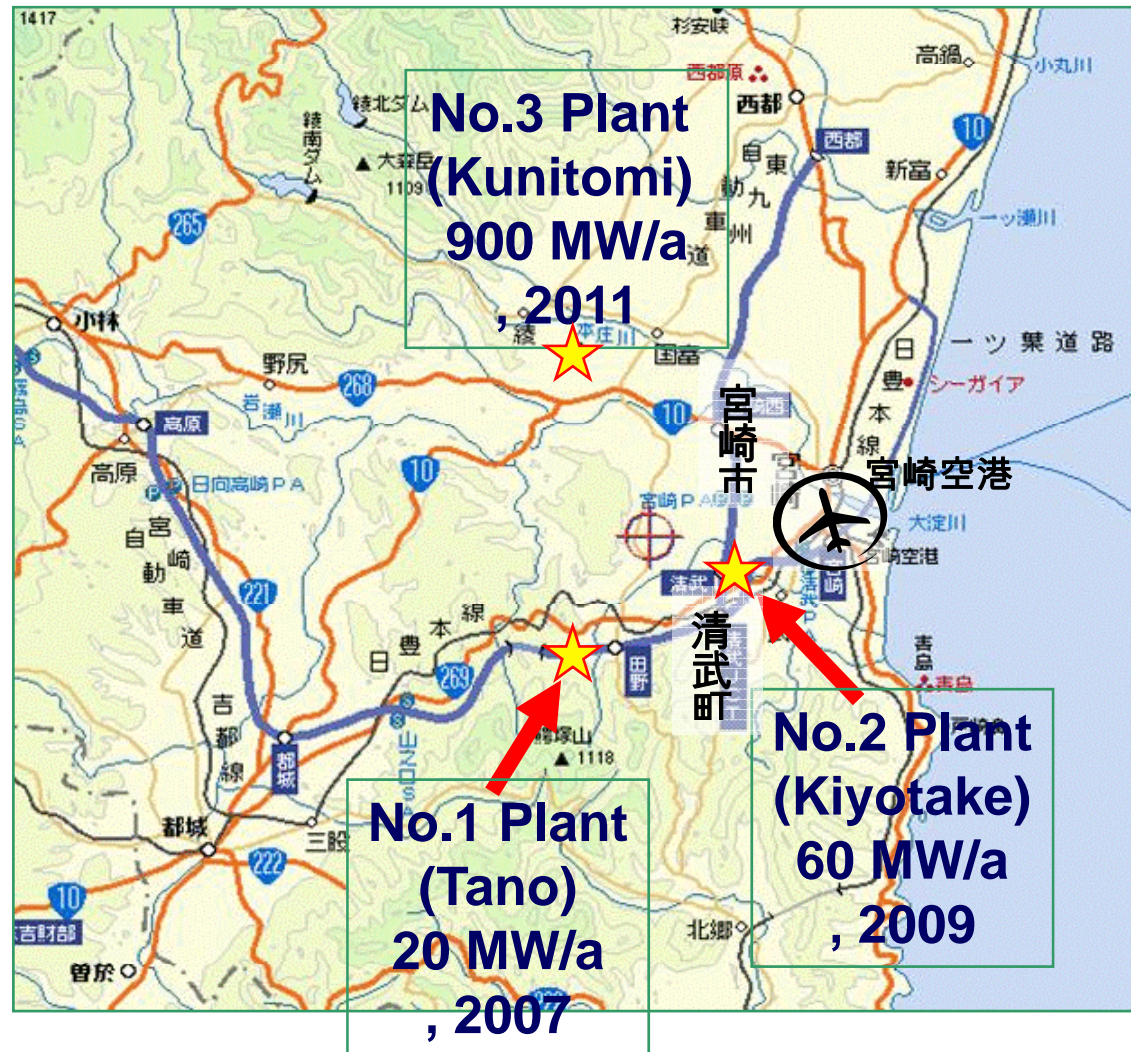
2009: Open the Atsugi Research Center.

2010: Change the company name to Solar Frontier K.K.

2011: Will start the mass-production of CIS-based thin-film PV modules in the 3rd plant of 900 MW/a, which means Solar Frontier will be a company with one GW/a production capacity.

- **It was done to be a company with two energy sources, oil and Solar-PV.**
- **It will be on the way to be a company on the net profit by FY-2014, 50 billion yen by Oil business and 50 billion yen by Solar-PV business.**

CIS Plant Location



Production Capacity

Solar Frontier K.K. is the company exclusively manufacturing the CIS-based thin-film PV modules with a Cd-free $Zn(O,S,OH)_x$ buffer layer.

20 MW/a
Plant



No. 1 Plant (Tano)
Start up: October 2006

60 MW/a
Plant



No. 2 Plant (Kiyotake)
Start up: November 2008

900 MW/a
Plant



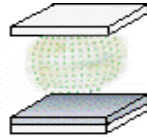
No. 3 Plant (Kunitomi)
Start up: February 2011 (No. 1 Line),
March 2011 (No. 2 Line)

Home page: <http://www.solar-frontier.com/>

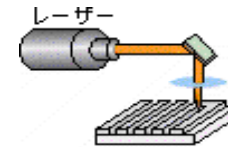
Full operation will be started by mid-2011.

Baseline Process

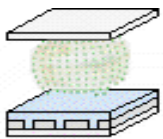
Substrate preparation
<Glass Wash>



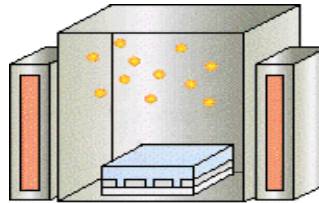
Metal Base Electrode
<DC Magnetron Sputtering>



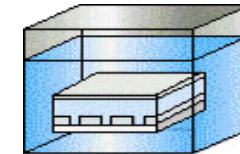
Pattern 1
<Laser Scribing>



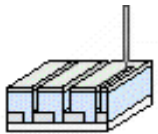
Metal Precursor
<DC Magnetron Sputtering>



p-type CIS-based Absorber
<**Sulfurization after Selenization**>



High-resistivity **Zn(O,S,OH)_x** Buffer
<Chemical-bath Deposition>



Pattern 2
<Mechanical Scribing>

n-type BZO Window
<**MOCVD**>

Pattern 3
<Mechanical Scribing>

Finishing

Packaging: Same technology as Crystalline-Si solar cells

Device Structure

Company	p type Absorber	n type layers	Substrate
Würth Solar	Coevaporation CIGSe ₂	CBD-CdS Sputtering-AZO	Glass
Solibro			
Global Solar Energy			Stainless steel foil
<u>Solar Frontier</u>	<u>SAS</u> CIGSe ₂ with CIG(Se,S) ₂ Surface layer	<u>CBD-Zn(O,S,OH)_x</u> <u>MOCVD-BZO</u>	Glass
Bosch Solar CISTech	SAS CIG(Se,S) ₂	CBD-CdS Sputtering-AZO	
AVANCIS	RTP-Simultaneous Selenization&Sulfurization CIG(Se,S) ₂	CBD-CdS Sputtering-AZO	
Honda Soltec	Selenization CIGSe ₂	<u>CBD-In(S,OH)_x</u> Sputtering-AZO	

Better position of SAS process

Better position	Reasons
<p>Since <u>highly reactive gas</u> can be used, drastic reduction of Se consumption is possible.</p>	<p>Required Se amount is estimated at about 1/40 of solid Se case. (Excellent materials saving)</p>
<p>Metal precursor layers can be prepared by <u>DC magnetron sputtering</u>, which is a proven technology on the excellent thickness control and high rate deposition. As the result, thinner CIS-based absorber is possible in a controlled thickness range of 1.2 to 1.5 micron.</p>	<p>CIS-based absorber thickness in the commercialization is estimated as at least 0.5 micron thinner than Coevaporated ones. (Excellent materials saving)</p>
<p><u>End-of-life sputtering targets</u> can be recycled, because of no contamination.</p>	<p>Sputtering targets are in the recycle flow. (Excellent materials saving and cost reduction)</p>
<p>60cmx120cm size is a current standard, but <u>Solar Frontier K.K. will use a 90cmx120cm size substrate in the 900 MW production.</u></p>	<p><u>Substrate size will be larger than CdTe, but smaller than a-Si.</u></p>

R&D in the NEDO Solar-PV R&D Projects

Single cell with Top grids



Monolithically Integrated Circuit

1cm² →

Test Structure: 3.2cm²

(16 cells) on 10cmx10cm (100cm²)

50cm² on 100cm² → 80cm² on 100cm²

→ 10cmx30cm (300cm²)

→ 30cmx30cm (1footx1foot, 900cm²)

→ 30cmx120cm (1footx4feet, 3,600cm²)

**20 MW/a
Plant**

60cmx120cm

(2feetx4feet, 7,200cm²)

**60 MW/a
Plant**

**900 MW/a
Plant**

90cmx120cm

(3feetx4feet, 10,800cm²)

Improvement of Output: Reality

Period	Rated Power [W_p] on <u>Catalogue</u> base	Miyazaki Plant
From Apr., 2007 To Apr., 2009	<p>70 75</p> <p>w/ JET, TUV & UL</p> <p>2x4 size</p>	No.1
From Sep., 2009 To Today	<p>80 85</p> <p>90 Export only</p>	No.2
From Apr., 2011	<p>3x4 size</p> <p>130 140</p> <p>w/ JET, TUV & UL</p> <p><i>150W is coming soon.</i></p>	No.3



Roof-top Application in Japan

Mega Solar: 1 Mega Solar-PV Power System
in Miyazaki No.2 Plant

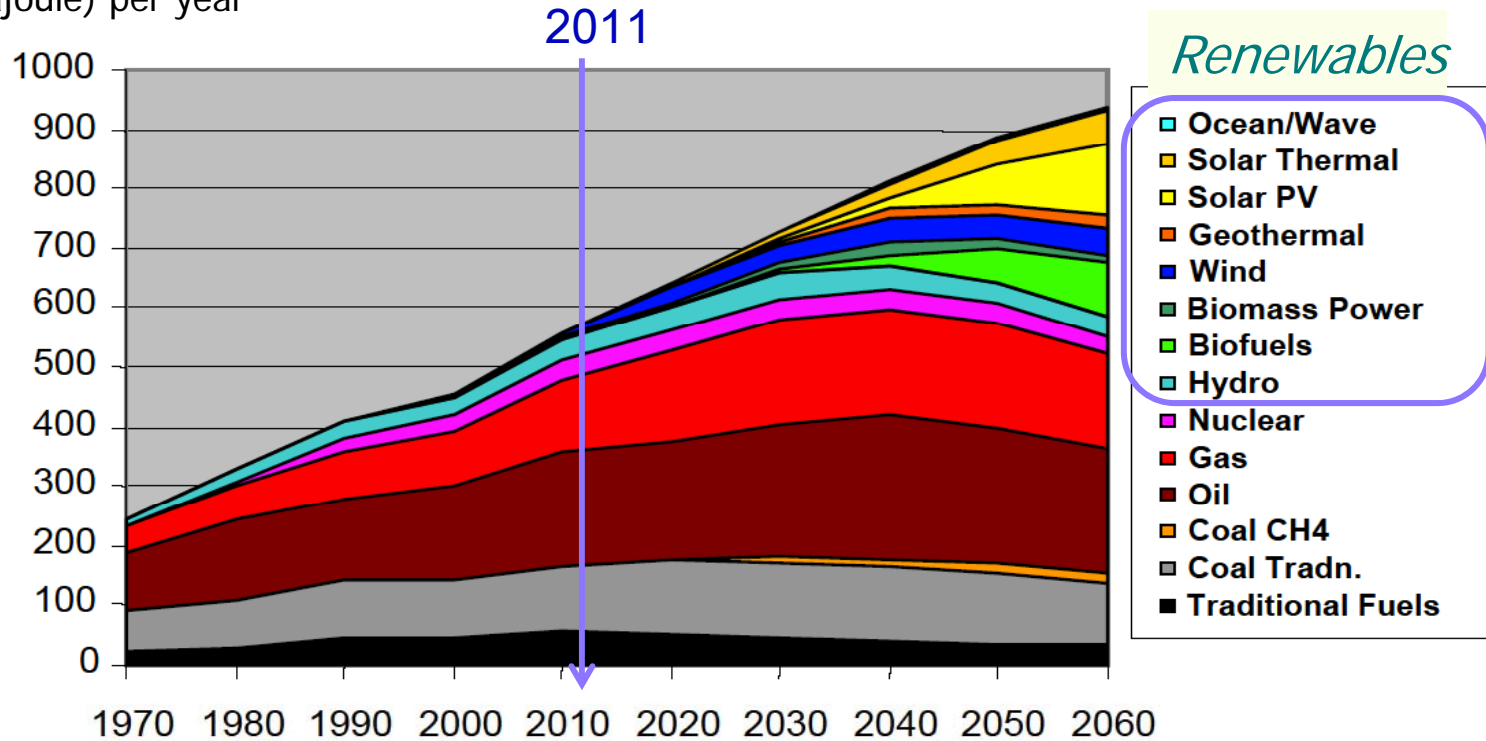


- Current Status
- **Future Prospect**
- **Conclusions**

Toward the Energy mix era: (Trend of global primary energy demand)

Shell's long term scenario – a transition to renewables

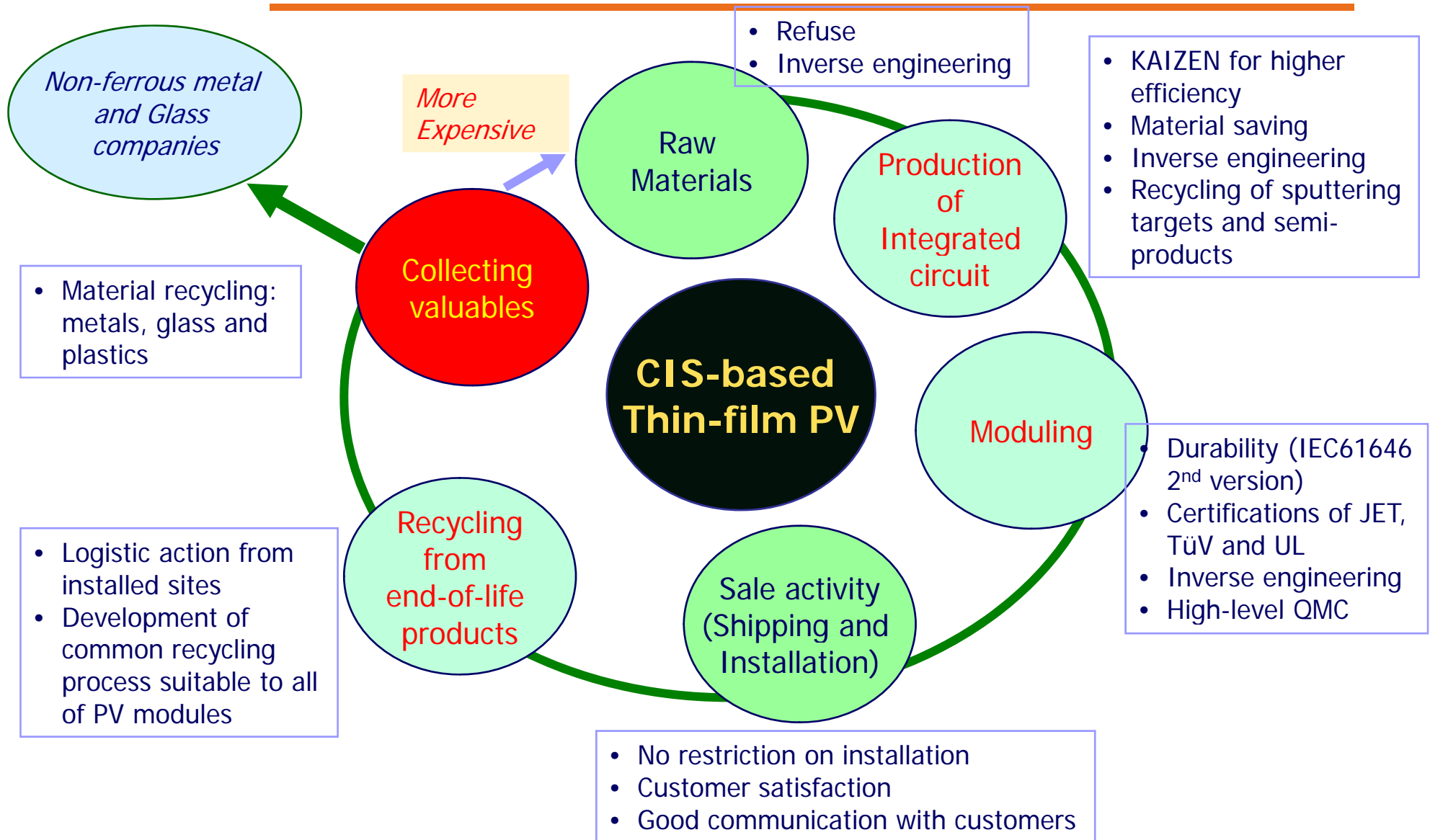
Ej (exajoule) per year



Shell Long Term Energy Scenario 'Dynamics as Usual'

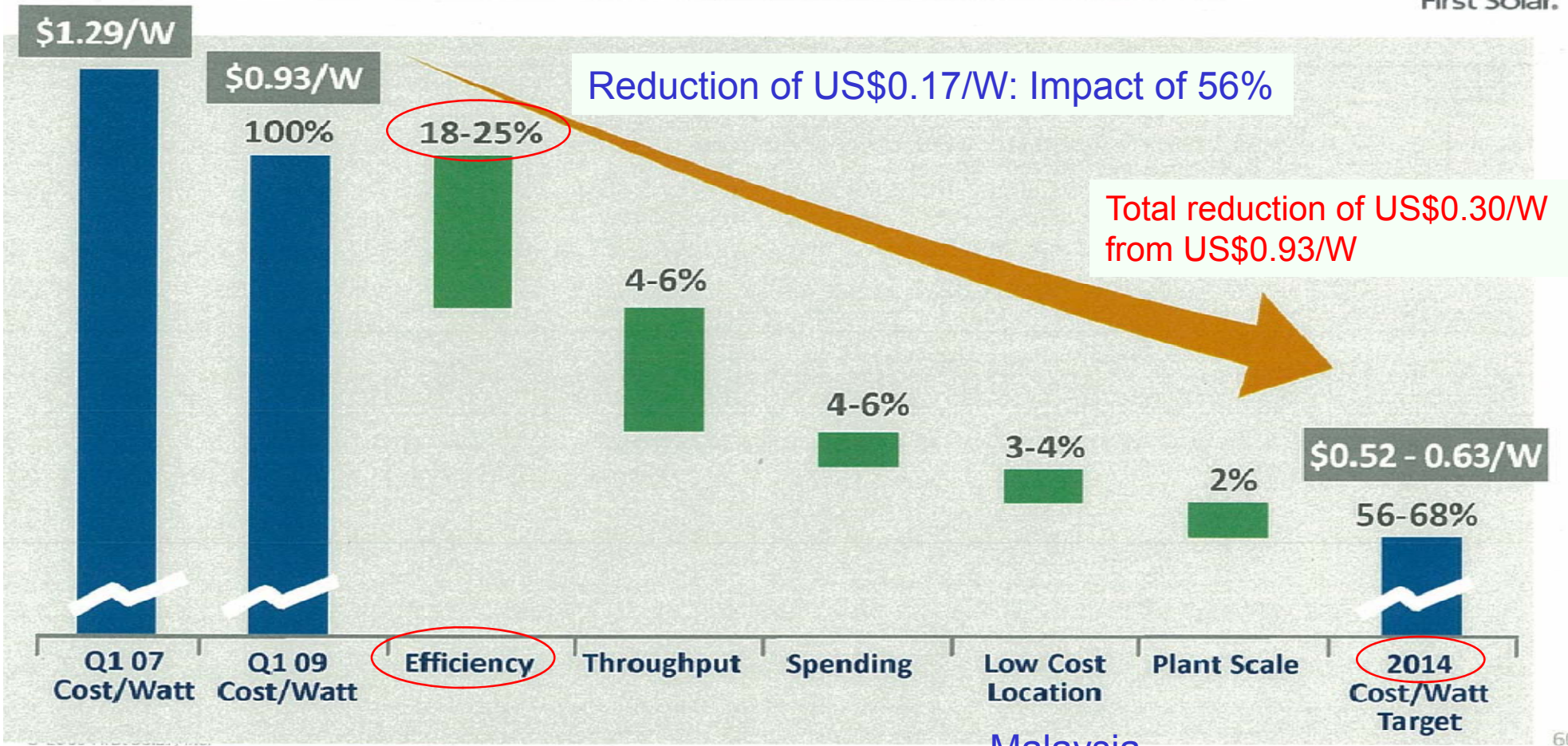


Shell Renewables



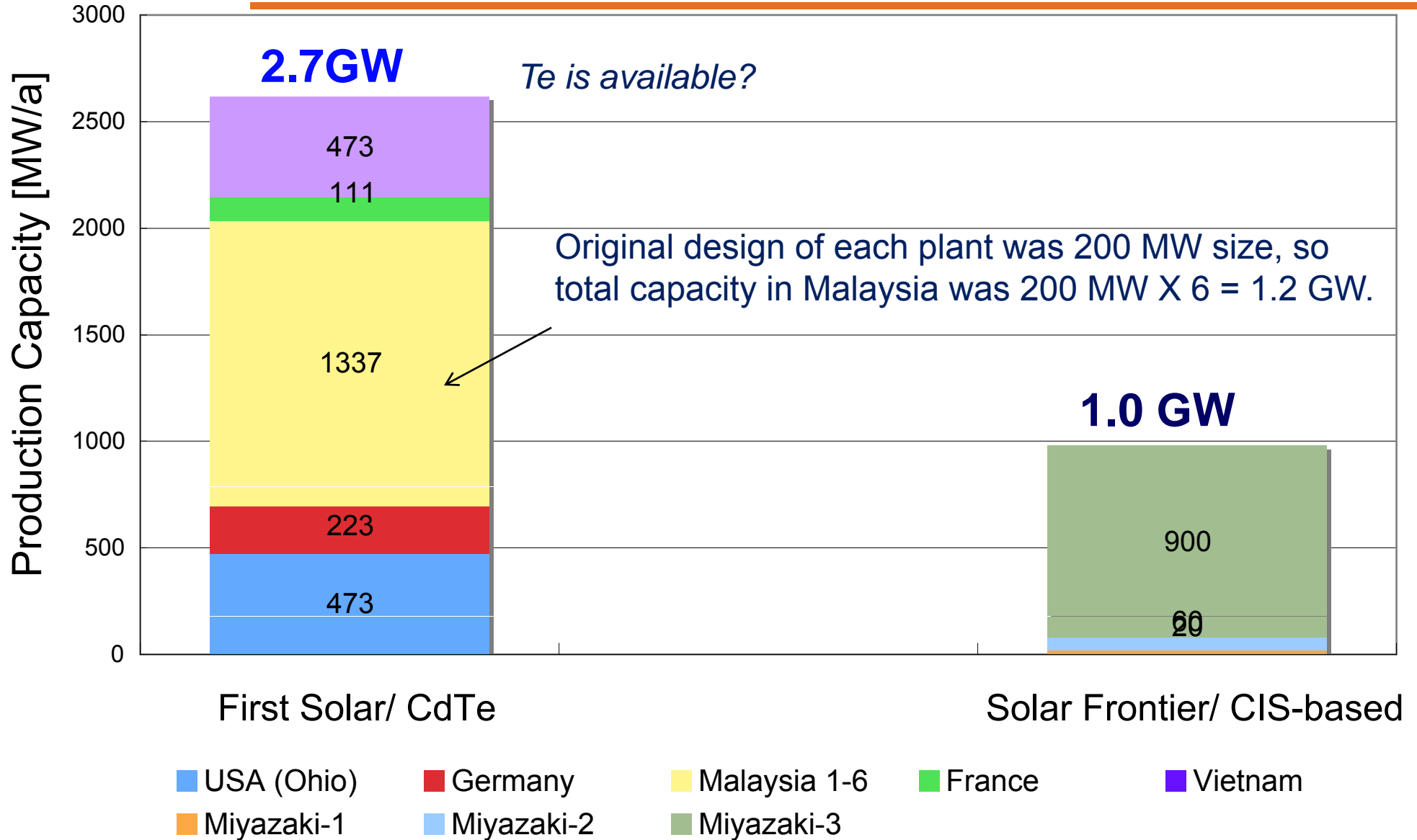
First Solar, Price Leader

Their basic understanding is it is necessary to improve the efficiency for mfg cost down.



Malaysia

Production Capacity in 2012



World-record efficiency

Size	CIS-based/ Glass substrate	CdTe/ Glass substrate
Small-area single cell (Total-area)	<ul style="list-style-type: none"> • 20.0 % (0.419cm²) Oct. 2007 • 19.4 % (0.994cm²) Jul. 2008 Achieved by <u>NREL</u> , CdS buffer <ul style="list-style-type: none"> • 20.3 % (0.5cm²) Aug. 2010 Achieved by <u>ZSW</u> , CdS buffer	<ul style="list-style-type: none"> • 16.7 % (1.032cm²) Sep. 2001 Achieved by <u>NREL</u> (Main researchers left the NREL started up the venture company, PrimeStar Solar, which was invested by GE.)
Large-area (Over 800 cm ²) module (Aperture-area)	<ul style="list-style-type: none"> • 14.2 % (6840cm²) Jun. 2010 Achieved by <u>Solibro</u> , CdS buffer <ul style="list-style-type: none"> • 15.7% (9703cm²) Nov. 2010 Achieved by <u>Miasole</u> , CdS buffer <ul style="list-style-type: none"> • 13.5 % (3459cm²) Aug. 2002 • 17.2 % (819cm²) Mar. 2011 Achieved by <u>Showa Shell Sekiyu</u> , Zn(O,S,OH) _x buffer	<ul style="list-style-type: none"> • 10.9 % (4874cm²) Apr. 2000 Achieved by <u>BP Solarex</u> , who trashed their CdTe technology later.



Champion Efficiency

Goal for Current NEDO Project is **18%** on 900cm² (1x1), which would be translated into **16%** on 10,800cm² (3x4).

Aperture Area [cm ²]	Efficiency [%]	Output [W _p]	Measured by
819	17.2 * +	14.1	Showa Shell
839	16.3 * +	13.9	Showa Shell
815	15.8 * +	12.9	AIST
3,456	13.6 * +	47.0	Showa Shell
3,459	13.5 * + Certified World Record/ Cd free	46.9	NREL
7,128	13.1 **	<u>93.1</u>	AIST

* Submodule, + NEDO Solar-PV R&D projects), ** Module sourced from the production line of Solar Frontier's Miyazaki 20 MW/a plant.

To improve the quality

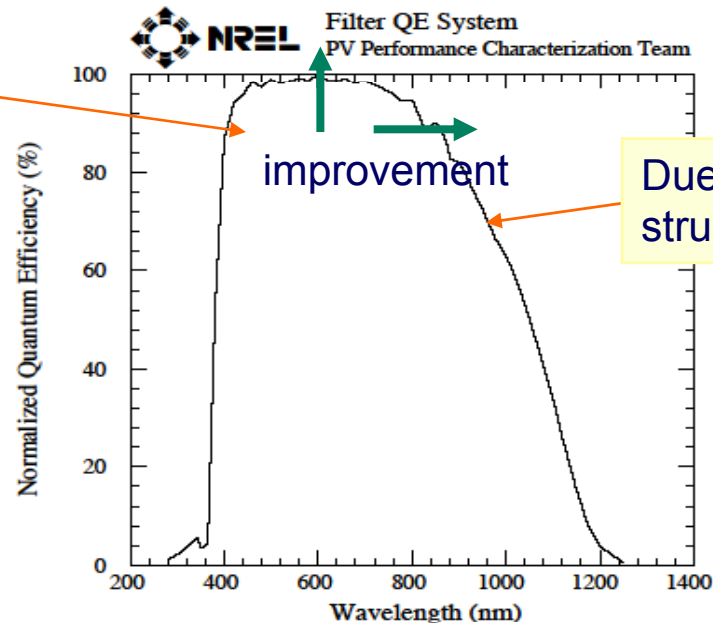
Showa Shell

Zn(O,S,OH)_x buffer/Cu(InGa)(SSe)₂ module

Device ID: 8M-381
Sep 13, 2001 12:03 PM

Device Temperature: 25.0 ± 1 °C
Device Area: 856.8 cm²

Due to the wide-gap Zn(O,S,OH)_x buffer



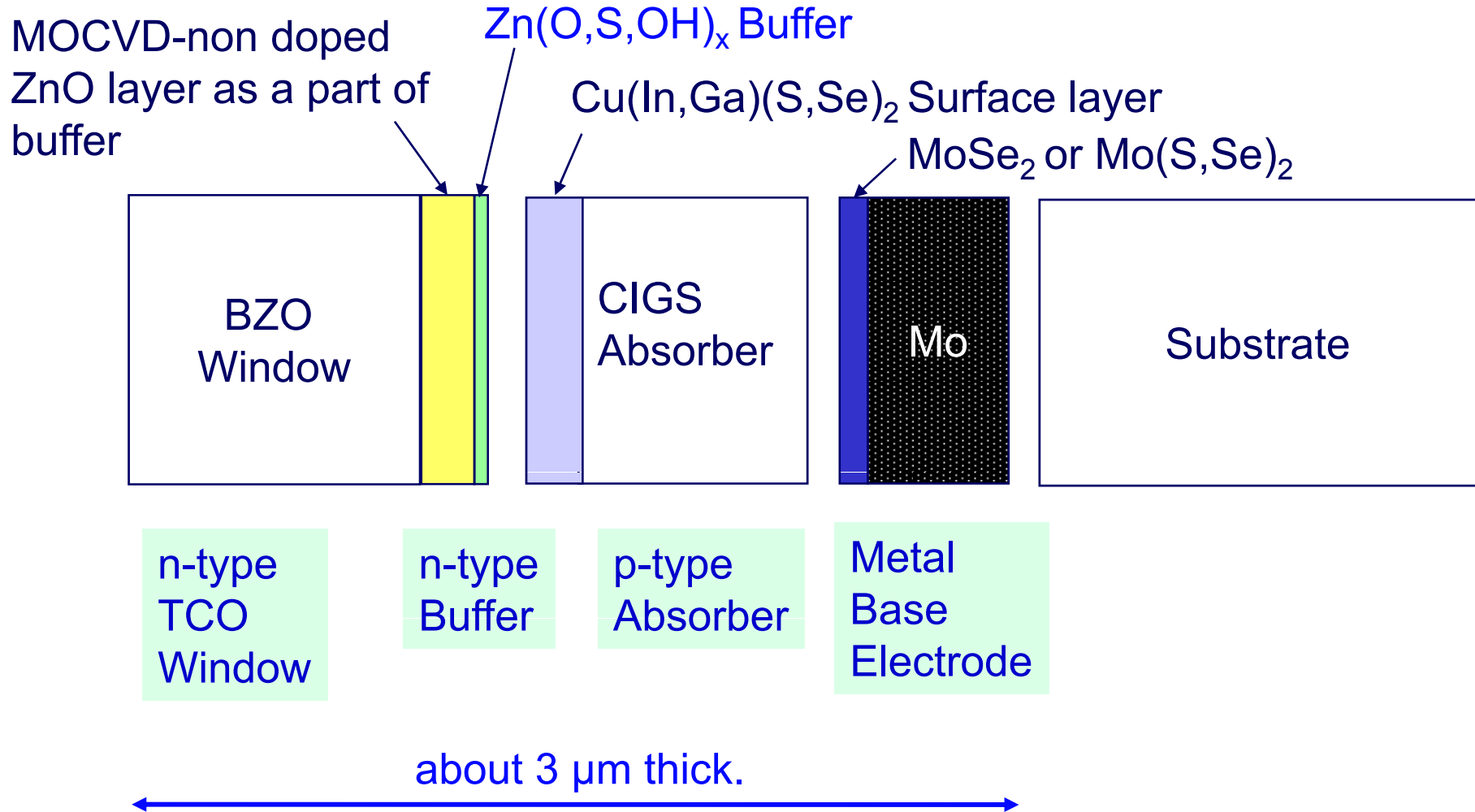
Due to the graded band-gap structure of CIS-based absorber

- 1) Improve the quality of CIS-based absorber.
- 2) Reduce the dead area related to the patterning.
- 3) Improve the quality of pn hetero-junction.
- 4) Improve the mobility of TCO window layer.

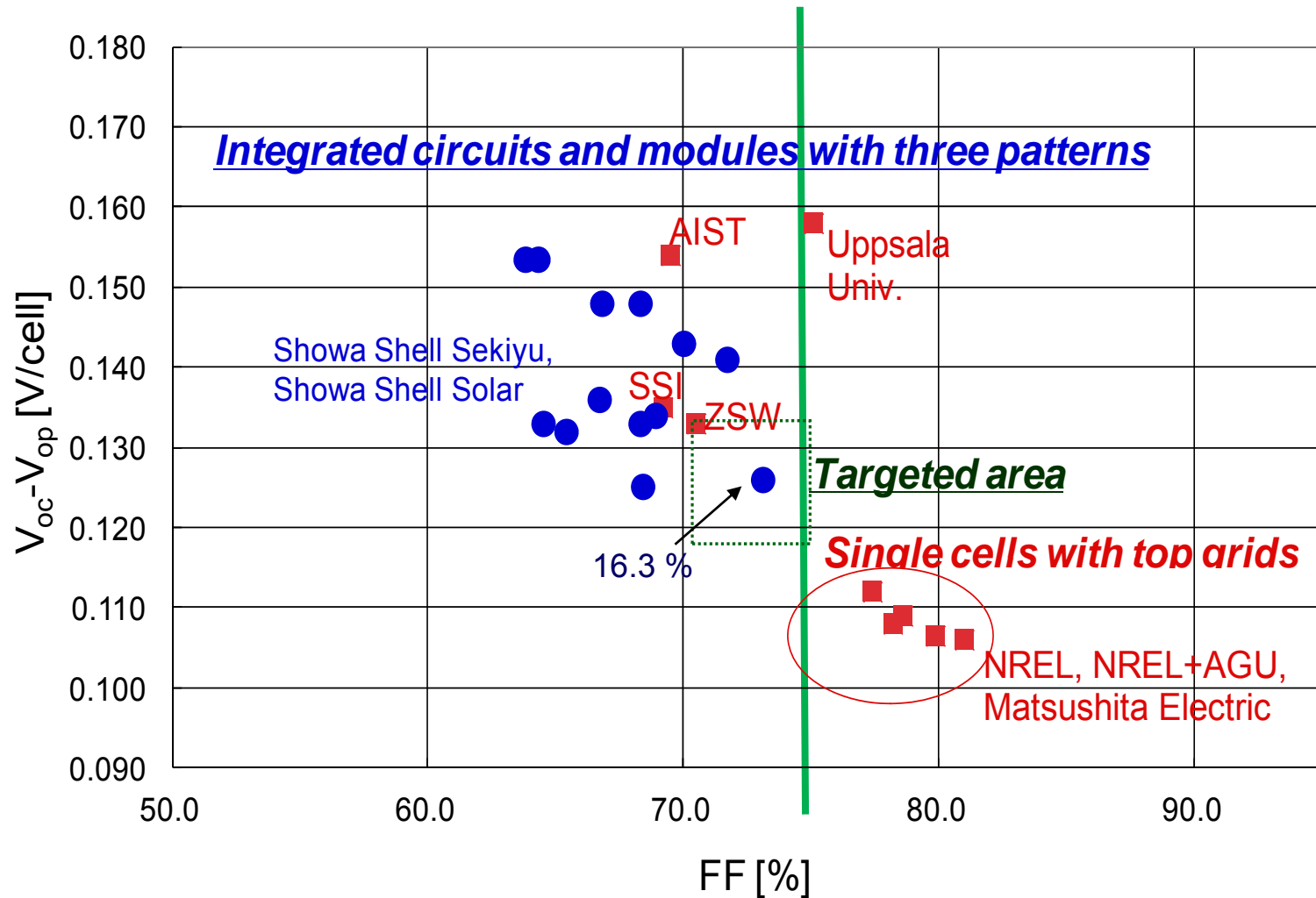
Voltage Bias: 0.0 V
Light bias for 23.6 mA
Light Bias region area: 49.00 cm²
Light Bias Density: 0.4810 mA/cm²

similar to 13.4% module 8N8486198240

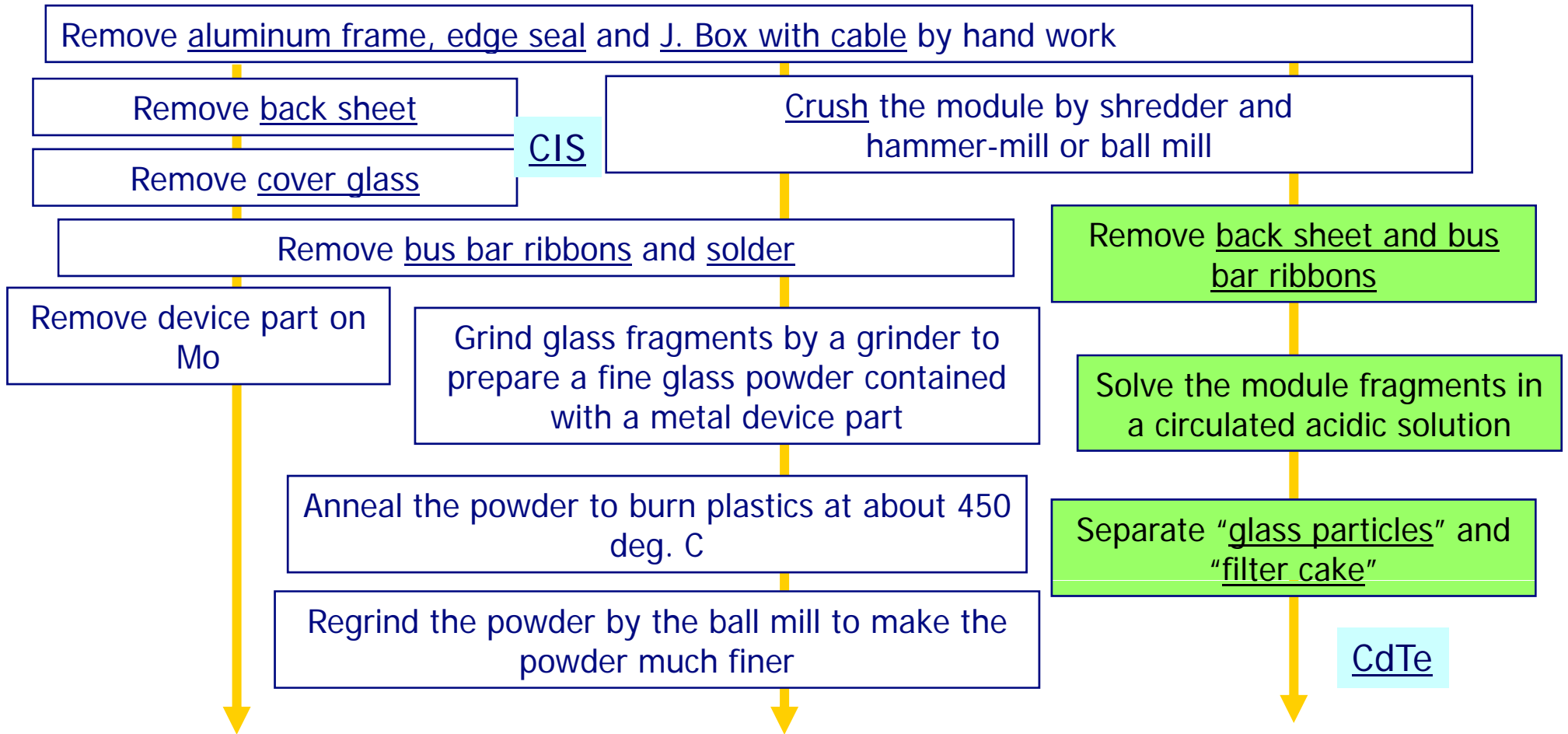
Device Structure



FF vs. ($V_{oc}-V_{op}$) [V/cell]

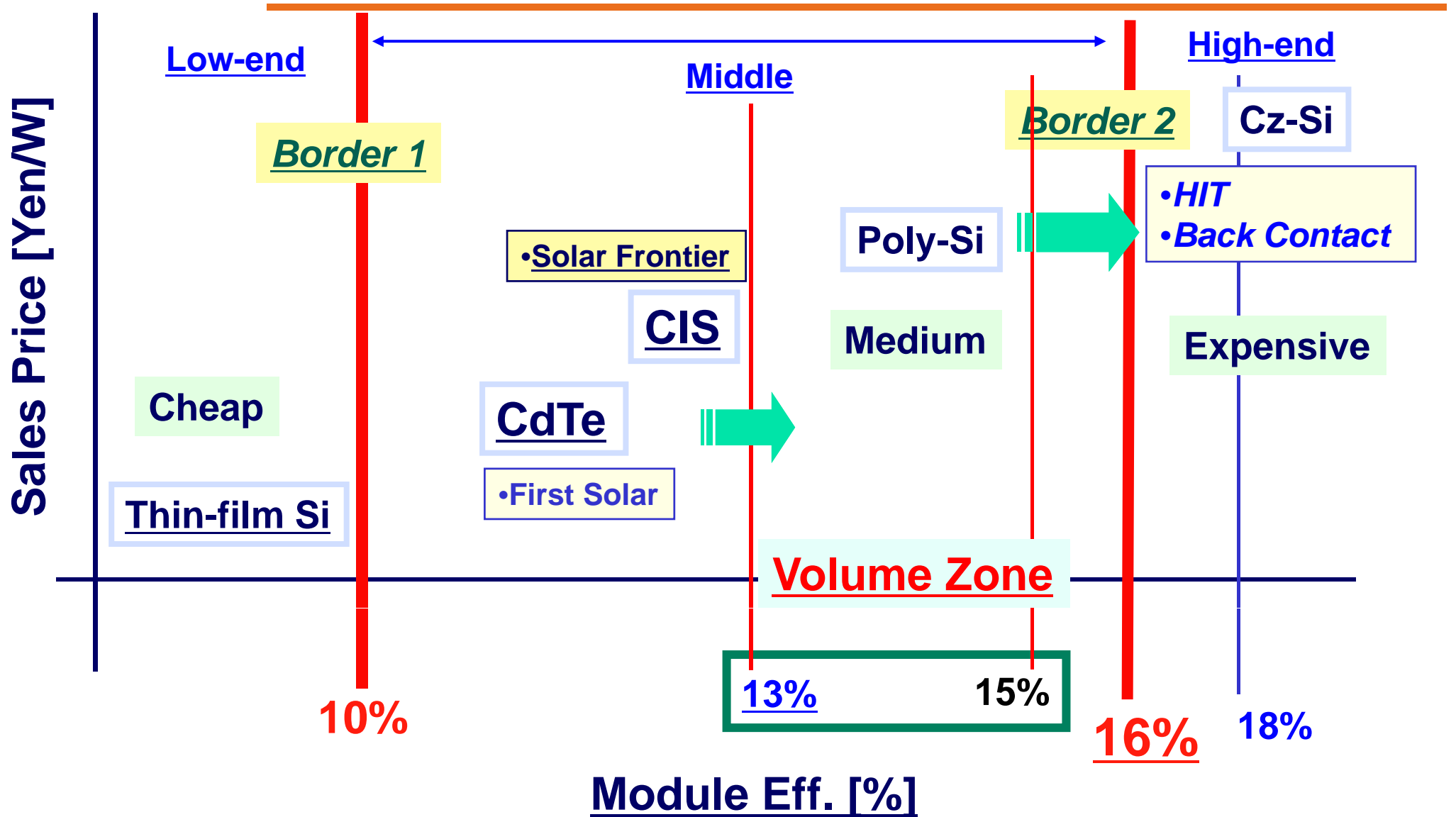


Recycle process (Patent pending)



- Collected metal powder or filter cake is shipped to non-ferrous metal companies on a ton base.
- Glass substrates with an Mo base electrode or glass particles are shipped to glass companies as a glass cullet.
- This was confirmed by AGC and contributes to reduce the recycle cost.

PV Market: Three Zones



What we should do is

- 1) to improve the module efficiency in the commercial production.
- 2) to achieve the 18% efficiency on a 900cm²-sized substrate in the R&D activities.
- 3) to transfer the R&D technology to the commercial production quickly and smoothly.